

- 1N5711 AVAILABLE IN JANHC AND JANKC PER MIL-PRF-19500/444
- 1N5712 AVAILABLE IN JANHC AND JANKC PER MIL-PRF-19500/445
- SCHOTTKY BARRIER DIODE CHIPS FOR GENERAL PURPOSE APPLICATION
- SILICON DIOXIDE PASSIVATED
- COMPATIBLE WITH ALL WIRE BONDING AND DIE ATTACH TECHNIQUES,

CD2810
 CD5711
 CD5712
 CD6857
 CD6858
 CD6916

MAXIMUM RATINGS

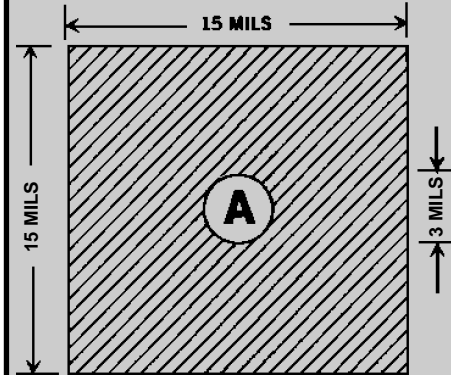
Operating Temperature: -55°C to +125°C
 Storage Temperature: -65°C to +150°C

ELECTRICAL CHARACTERISTICS @ 25°C, unless otherwise specified

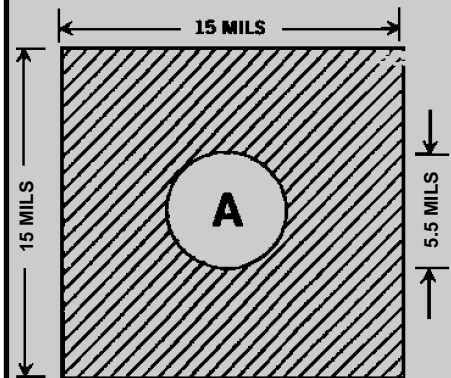
CDI TYPE NUMBER	MINIMUM BREAKDOWN VOLTAGE (2)	MAXIMUM FORWARD VOLTAGE	MAXIMUM FORWARD VOLTAGE	MAXIMUM REVERSE LEAKAGE CURRENT		MAXIMUM CAPACITANCE @ $V_R = 0$ VOLTS $f = 1.0$ MHz	FIGURE NUMBER
	$V_{BR} @ 10 \mu A$	$V_F @ 1 mA$	$V_F @ I_F$	$I_R @ V_R$		C_T	
	VOLTS	VOLTS	VOLTS @ mA	nA	VOLTS	PICO FARADS	
CD2810	20	0.41	1.0 @ 35	100	15	1.2	1
CD5711	70	0.41	1.0 @ 15	200	50	2.0	2
CD5712	20	0.41	1.0 @ 35	150	16	1.2	1
CD6857	20	0.35	0.75 @ 35	150	16	4.5	2
CD6858	70	0.36	0.65 @ 15	200	50	4.5	2
CD6916	40 (2)	0.34	0.27 @ 0.1	100	1	5	2
			0.34 @ 1.0	200	20		
			0.47 @ 10.0	500	40		

NOTES: (1) Effective Minority Carrier Lifetime (τ) is 100 Pico Seconds

(2) CD6916 V_{BR} measured @ 500 nanoamps



BACKSIDE IS CATHODE
 FIGURE 1



BACKSIDE IS CATHODE
 FIGURE 2

DESIGN DATA

METALLIZATION:

Top: (Anode).....Au
 Back: (Cathode).....Au

AL THICKNESS.....25,000 Å Min

GOLD THICKNESS.....4,000 Å Min

CHIP THICKNESS.....10 Mils

TOLERANCES: ALL Dimensions
 ± 2 mils, Except Anode Pad Where
 Tolerance is ± 0.5 mils.



CD2810, CD5711, CD5712, CD6857, CD6858 and CD6916

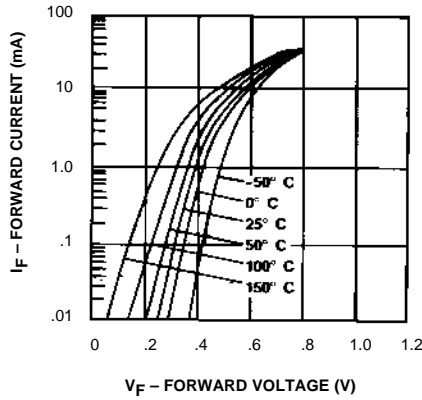


Figure 1.
I-V Curve Showing Typical Forward Voltage Variation with Temperature for the CD5712 and CD2810 Schottky Diodes.

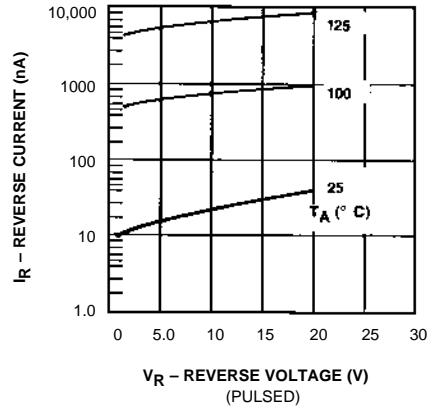


Figure 2.
CD5712 and CD2810
Typical Variation of Reverse Current (I_R) vs. Reverse Voltage (V_R) at Various Temperatures.

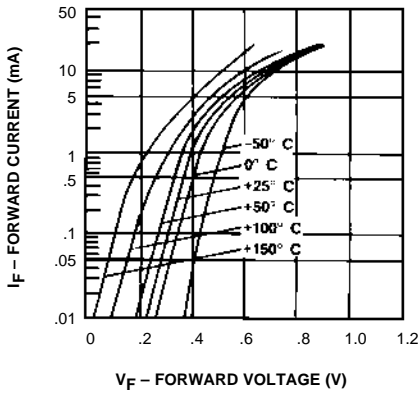


Figure 3.
I-V Curve Showing Typical Forward Voltage Variation with Temperature for Schottky Diode CD5711.

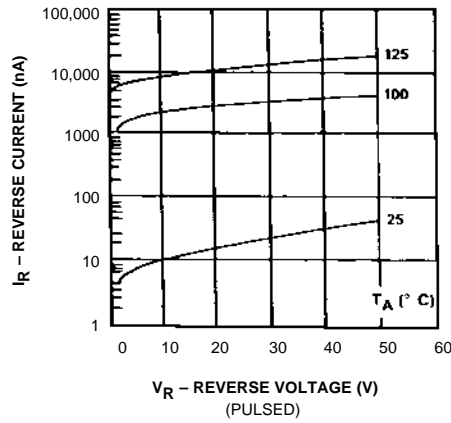


Figure 4.
CD5711 Typical Variation of Reverse Current (I_R) vs. Reverse Voltage (V_R) at Various Temperatures.

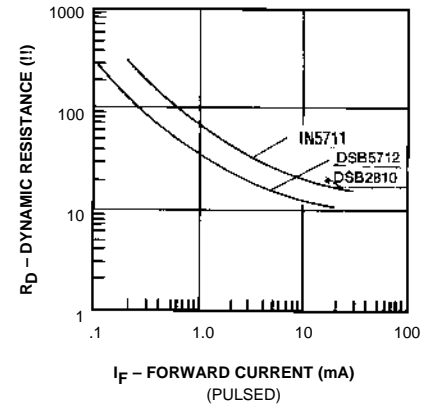


Figure 5.
Typical Dynamic Resistance (R_D) vs. Forward Current (I_F).